

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	7334	reflect\$4 with gate	USPAT; US-PGPUB; EPO; JPO; DERWENT
2	BRS	L2	2445 97	(reflect\$4 with gate or electrode) same material	USPAT; US-PGPUB; EPO; JPO; DERWENT
3	BRS	L3	1769 95	2 and @ad<=19981118	USPAT; US-PGPUB; EPO; JPO; DERWENT
4	BRS	L4	1509 01	3 and @pd<=19981118	USPAT; US-PGPUB; EPO; JPO; DERWENT
5	BRS	L5	3883 0	4 and switching adj element or TFTS or thin adj film adj transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT
6	BRS	L6	2207 4	5 and liquid adj crystal	USPAT; US-PGPUB; EPO; JPO; DERWENT
7	BRS	L7	1509 01	3 and 4	USPAT; US-PGPUB; EPO; JPO; DERWENT
8	BRS	L8	1040 2	7 and liquid adj crystal	USPAT; US-PGPUB; EPO; JPO; DERWENT
9	BRS	L9	996	349/42,43,46.ccls.	USPAT
10	BRS	L10	840	2 and 1	USPAT
11	BRS	L11	559	10 and @ad<=19981118	USPAT; US-PGPUB; EPO; JPO; DERWENT